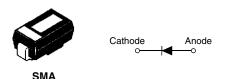


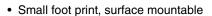
Vishay High Power Products

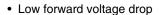
Schottky Rectifier, 2.1 A



PRODUCT SUMMARY			
I _{F(AV)}	2.1 A		
V_{R}	60 V		

FEATURES







- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS directive 2002/95/EC
- · Designed and qualified for industrial level

DESCRIPTION

The 10MQ060NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	DC	2.1	A	
V _{RRM}		60	V	
I _{FSM}	t _p = 5 μs sine	40	A	
V _F	1.5 Apk, T _J = 125 °C	0.63	V	
TJ	Range	- 55 to 150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	10MQ060NPbF	UNITS	
Maximum DC reverse voltage	V_{R}	60	V	
Maximum working peak reverse voltage	V_{RWM}	60	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T_L = 120 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1.5	А
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	40	Α
non-repetitive surge current See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	10	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 4 \text{mH}$		2.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	Α

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Vishay High Power Products Schottky Rectifier, 2.1 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _{.1} = 25 °C	0.63	V
		1.5 A	11=25 0	0.71	
		1 A	T _{.1} = 125 °C	0.57	
		1.5 A	TJ = 125 C	0.63	
Maximum reverse leakage current	current I _{RM} (1)	T _J = 25 °C	$V_B = Rated V_B$	0.5	mA
See fig. 2	'RM \''	T _J = 125 °C	v _R = nateu v _R	7.5	
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J} \text{ maximum}$ 0.45 86.8		0.45	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	C _T	$V_R = 10 V_{DC}$, $T_J = 25 ^{\circ}$ C, test signal = 1 MHz		31	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 0		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
		0.002	OZ.	
Marking device		Case style SMA (similar D-64)	V1	Н

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$



Schottky Rectifier, 2.1 A Vishay High Power Products

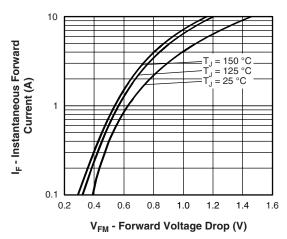


Fig. 1 - Maximum Forward Voltage Drop Characteristics

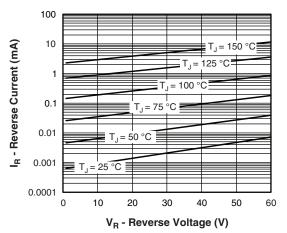


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

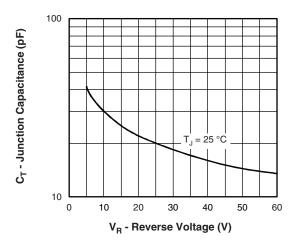


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

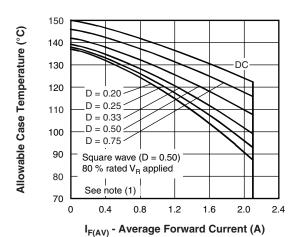
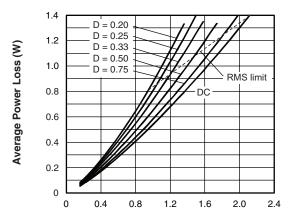
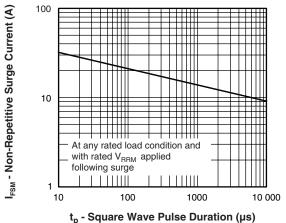


Fig. 4 - Maximum Average Forward Current vs.
Allowable Lead Temperature



I_{F(AV)} - Average Forward Current (A)
Fig. 5 - Maximum Average Forward Dissipation vs.
Average Forward Current



tp oquale wave raise baration (µs)

Fig. 6 - Maximum Peak Surge Forward Current vs.
Pulse Duration

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

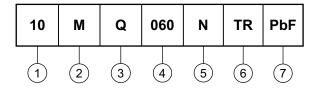
10MQ060NPbF

Vishay High Power Products Schottky Rectifier, 2.1 A



ORDERING INFORMATION TABLE

Device code



- 1 Current rating
- 2 M = SMA
- 3 Q = Schottky "Q" series
- Voltage rating (060 = 60 V)
- 5 N = New SMA
- • None = Box (1000 pieces)
 - TR = Tape and reel (7500 pieces)
- 7 PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95018		
Part marking information	www.vishay.com/doc?95029		
Packaging information	www.vishay.com/doc?95034		





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